

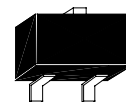


HBC847

NPN EPITAXIAL PLANAR TRANSISTOR

Description

The HBC847 is designed for switching and AF amplifier amplification suitable for automatic insertion in thick and thin-film circuits.



SOT-23

Absolute Maximum Ratings

- Maximum Temperatures
Storage Temperature..... -55 to +150 °C
Junction Temperature..... +150 °C
- Maximum Power Dissipation
Total Power Dissipation ($T_A=25^{\circ}\text{C}$)..... 225 mW
- Maximum Voltages and Currents ($T_A=25^{\circ}\text{C}$)
 V_{CBO} Collector to Base Voltage 50 V
 V_{CEO} Collector to Emitter Voltage 45 V
 V_{EBO} Emitter to Base Voltage 6 V
 I_C Collector Current 100 mA

Electrical Characteristics ($T_A=25^{\circ}\text{C}$)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV_{CBO}	50	-	-	V	$I_C=100\mu\text{A}$
BV_{CEO}	45	-	-	V	$I_C=1\text{mA}$
BV_{EBO}	6	-	-	V	$I_E=10\mu\text{A}$
I_{CBO}	-	-	15	nA	$V_{CB}=30\text{V}$
$*V_{CE(sat)1}$	-	90	250	mV	$I_C=10\text{mA}$, $I_B=0.5\text{mA}$
$*V_{CE(sat)2}$	-	200	600	mV	$I_C=100\text{mA}$, $I_B=5\text{mA}$
$*V_{BE(sat)1}$	-	700	-	mV	$I_C=10\text{mA}$, $I_B=0.5\text{mA}$
$*V_{BE(sat)2}$	-	900	-	mV	$I_C=100\text{mA}$, $I_B=5\text{mA}$
$V_{BE(on)1}$	580	-	700	mV	$V_{CE}=5\text{V}$, $I_C=2\text{mA}$
$V_{BE(on)2}$	-	-	770	mV	$V_{CE}=5\text{V}$, $I_C=10\text{mA}$
$*h_{FE}$	110	-	800		$V_{CE}=5\text{V}$, $I_C=2\text{mA}$
f_T	-	300	-	MHz	$V_{CE}=5\text{V}$, $I_C=10\text{mA}$
Cob	-	3.5	6	pF	$V_{CB}=10\text{V}$, $f=1\text{MHz}$, $I_E=0$

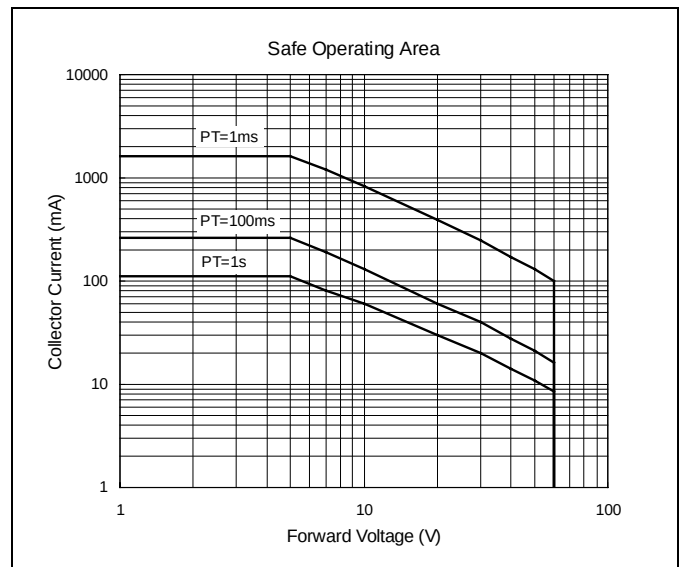
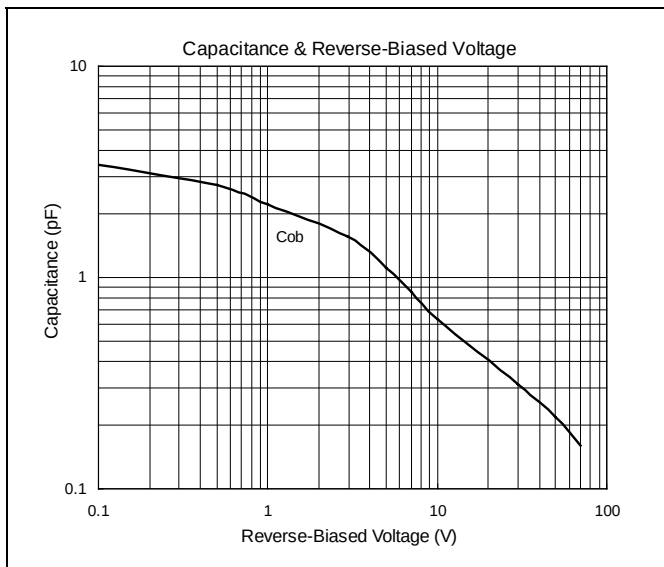
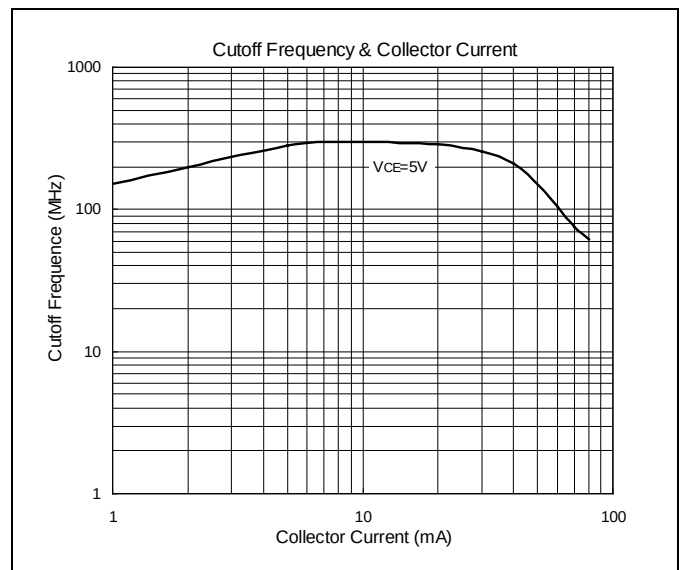
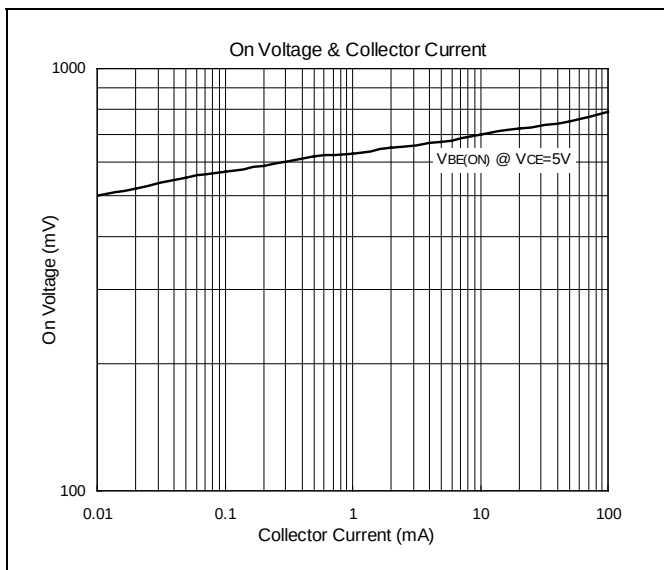
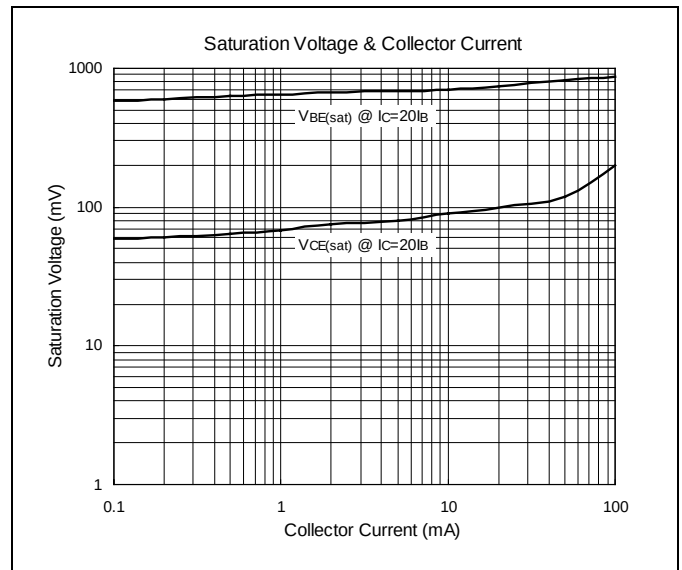
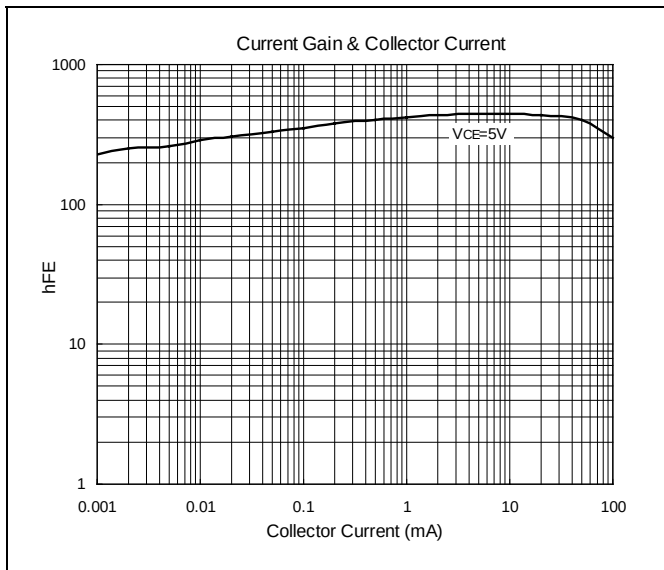
*Pulse Test: Pulse Width $\leq 380\mu\text{s}$, Duty Cycle $\leq 2\%$

Classification Of h_{FE}

Rank	8BA(A)	8BB(B)	8BC(C)
h_{FE}	110-220	200-450	420-800

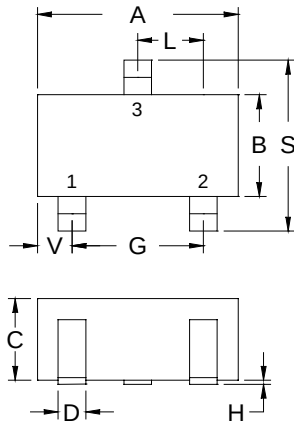


Characteristics Curve



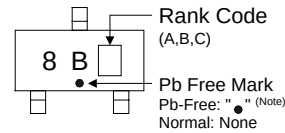


SOT-23 Dimension



3-Lead SOT-23 Plastic
Surface Mounted Package
HSMC Package Code: N

Marking:



Note: Pb-free product can distinguish by the green label or the extra description on the right side of the label.

Pin Style: 1.Base 2.Emitter 3.Collector

Material:

- Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

DIM	Min.	Max.
A	2.80	3.04
B	1.20	1.60
C	0.89	1.30
D	0.30	0.50
G	1.70	2.30
H	0.013	0.10
J	0.085	0.177
K	0.32	0.67
L	0.85	1.15
S	2.10	2.75
V	0.25	0.65

*: Typical, Unit: mm

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Head Office And Factory:

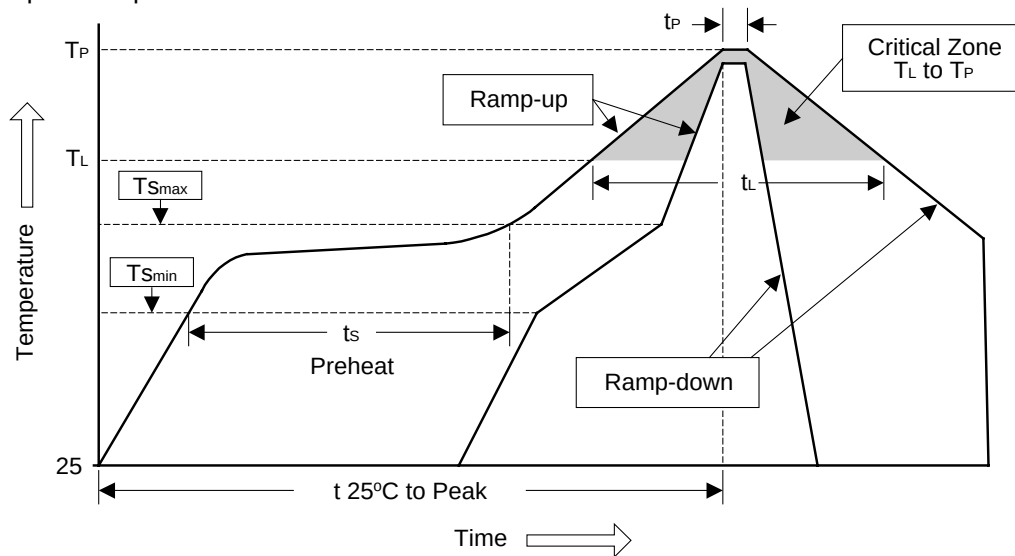
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Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices

Figure 1: Temperature profile



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	<3°C/sec	<3°C/sec
Preheat		
- Temperature Min (T_{smin})	100°C	150°C
- Temperature Max (T_{smax})	150°C	200°C
- Time (min to max) (t_s)	60~120 sec	60~180 sec
T_{smax} to T_L		
- Ramp-up Rate	<3°C/sec	<3°C/sec
Time maintained above:		
- Temperature (T_L)	183°C	217°C
- Time (t_L)	60~150 sec	60~150 sec
Peak Temperature (T_P)	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak Temperature (t_P)	10~30 sec	20~40 sec
Ramp-down Rate	<6°C/sec	<6°C/sec
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

3. Flow (wave) soldering (solder dipping)

Products	Peak temperature	Dipping time
Pb devices.	245°C ±5°C	5sec ±1sec
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec